# SB01-15C

# ON Semiconductor®

# Schottky Barrier Diode 150V, 0.1A, Low IR, Single CP

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### **Applications**

· High frequency rectification (switching regulators, converters, choppers)

### **Features**

- Low forward voltage (VF max=0.75V)
- · Low switching noise
- · Low leakage current and high reliability due to highly reliable planar structure

### **Specifications**

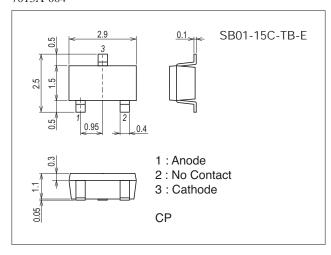
### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>		150	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		155	V
Average Output Current	IO		100	mA
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	5	А
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### **Package Dimensions**

unit : mm (typ) 7013A-004



### **Product & Package Information**

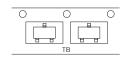
• Fast reverse recovery time (t<sub>rr</sub> max=10ns)

• Package : CP

• JEITA, JEDEC : SC-59, TO-236, SOT-23, TO-236AB

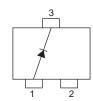
• Minimum Packing Quantity: 3,000 pcs./reel

### Packing Type: TB Marking





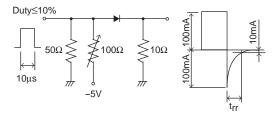
### **Electrical Connection**



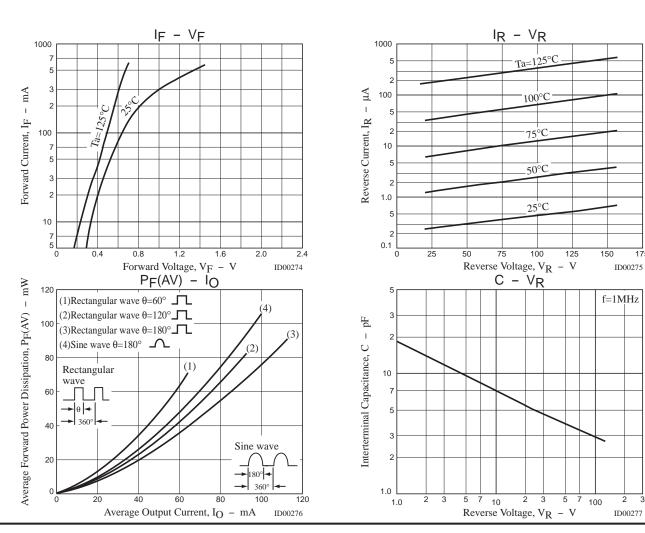
### Electrical Characteristics at Ta=25°C

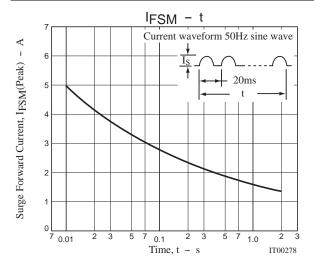
Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Symbol	Conditions	min	typ	max	Uill	
Reverse Voltage	VR	I <sub>R</sub> =200μA	150			V	
Forward Voltage	VF	I <sub>F</sub> =100mA			0.75	V	
Reverse Current	IR	V <sub>R</sub> =75V			50	μΑ	
Interterminal Capacitance	С	V <sub>R</sub> =10V, f=1MHz		7		pF	
Reverse Recovery Time	t <sub>rr</sub>	IF=IR=100mA, See specified Test Circuit.			10	ns	
	Rth(j-a)1			420		°C/W	
Thermal Resistance	Rth(j-a)2	Mounted in Cu-foiled area of 16mm <sup>2</sup> ×0.2mm	330			°C/W	
		on glass epoxy board		330		C / VV	

### trr Test Circuit



### **Ordering Information**



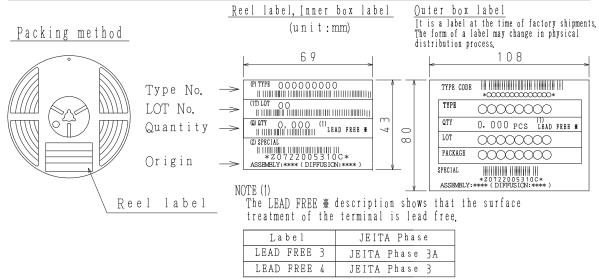


### **Embossed Taping Specification**

### SB01-15C-TB-E

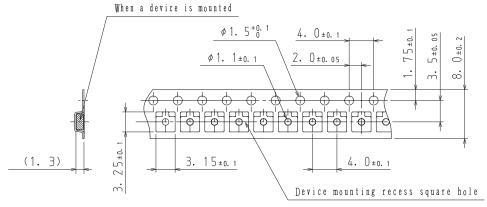
### 1. Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Туре	Reel	Inner box	Outer box	Inner $BOX(C-1)$	Outer BOX (A-7)	
СР	СР	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained	
					Dimensions:mm (external)	Dimensions:mm (external)	
					183×72×185	440×195×210	

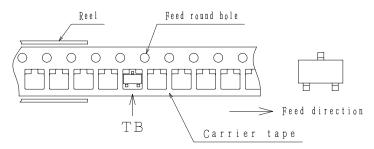


### 7. Taping configuration

2-1. Carrier tape size (unit:mm)



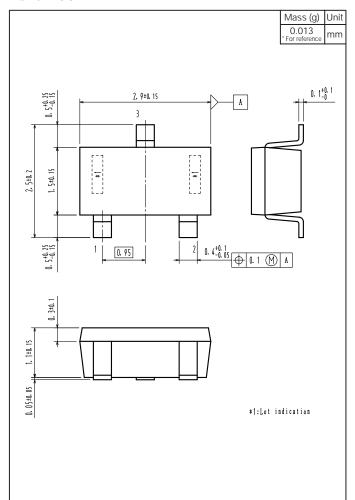
2-2. Device placement direction



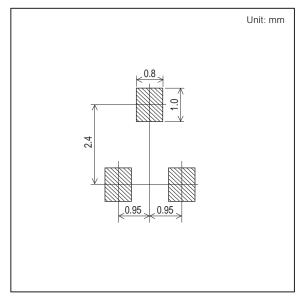
Those with one electrode terminal on the feed hole side·····TB

# Outline Drawing

SB01-15C-TB-E



### **Land Pattern Example**



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